

12V, 60mA Flash Memory Programming Supply

FEATURES

- Guaranteed 60mA Output
- Regulated 12V ±5% Output Voltage
- No Inductors
- Supply Voltage Range: 4.75V to 5.5V
- I_{CC} 0.5μA Typ in Shutdown
- Low Power: I_{CC} = 300μA
- 8-Pin SO Package
- Same Pinout as LTC1262 and MAX662

APPLICATIONS

- 12V Flash Memory Programming Supplies
- Compact 12V Op Amp Supplies
- Battery-Powered Systems

DESCRIPTION

The LTC®1263 is a regulated 12V, 60mA output DC/DC converter. It provides the 12V $\pm 5\%$ output necessary to program double byte-wide flash memories. The output provides 60mA from input voltages as low as 4.75V without using any inductors. Only four external capacitors are required to complete an extremely small, surface mountable circuit. The output can be momentarily shorted to ground without damaging the part.

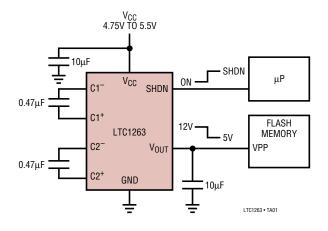
The active high TTL compatible Shutdown pin can be directly connected to a microprocessor. In the shutdown mode, the supply current typically drops to 0.5μ A.

The LTC1263 is available in an 8-pin SO package.

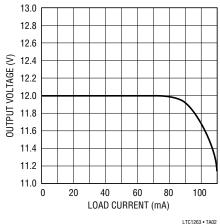
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TYPICAL APPLICATION

Flash Memory Programming Supply



Output Voltage vs Load



LTC1263 • TA02

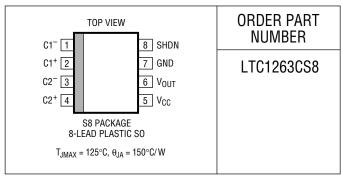


ABSOLUTE MAXIMUM RATINGS

(Note 1)

| Supply Voltage (V _{DD}) | 6V |
|-------------------------------------|---------------------------|
| Input Voltage (SHDN) | $0.3V$ to $V_{CC} + 0.3V$ |
| I _{OUT} Continuous | 90mA |
| Operating Temperature Range | 0°C to 70°C |
| Storage Temperature Range | 65°C to 150°C |
| Lead Temperature (Soldering, 10 sec |)300°C |

PACKAGE/ORDER INFORMATION



Consult factory for Industrial and Military grade parts and TSSOP package option.

ELECTRICAL CHARACTERISTICS $4.75V \le V_{CC} \le 5.5V$, $T_A = 0^{\circ}C$ to $70^{\circ}C$ (Notes 2, 3).

| SYMBOL | PARAMETER | CONDITIONS | | MIN | TYP | MAX | UNITS |
|---------------------|--|--|---|------|------|------|-------|
| V _{OUT} | Output Voltage | $0mA \le I_{OUT} \le 60mA$, $V_{SHDN} = 0V$ | • | 11.4 | | 12.6 | V |
| I _{CC} | Supply Current | No Load, V _{SHDN} = 0V | • | | 0.32 | 1.0 | mA |
| I _{SHDN} | Shutdown Supply Current | No Load, V _{SHDN} = V _{CC} | • | | 0.5 | 10 | μА |
| f _{OSC} | Oscillator Frequency | V _{CC} = 5V, I _{OUT} = 60mA | | | 300 | | kHz |
| | Power Efficiency | V _{CC} = 5V, I _{OUT} = 60mA | | | 76 | | % |
| R _{SW} | V _{CC} to V _{OUT} Switch Impedance | V _{CC} = V _{SHDN} = 5V, I _{OUT} = 0mA | • | | 0.3 | 1 | kΩ |
| $\overline{V_{IH}}$ | SHDN Input High Voltage | | • | 2.4 | | | V |
| V_{IL} | SHDN Input Low Voltage | | • | | | 0.8 | V |
| | SHDN Input Current | V _{CC} = 5V, V _{SHDN} = 0V | • | - 40 | - 20 | -5 | μА |
| | | V _{CC} = 5V, V _{SHDN} = 5V | • | -10 | 0 | 10 | μА |
| t _{ON} | Turn-On Time | C1 = C2 = 0.47μ F, C3 = C4 = 10μ F (Note 4) (Figures 1, 2) | | | 600 | | μS |
| t _{OFF} | Turn-Off Time | C1 = C2 = 0.47µF, C3 = C4 = 10µF (Figures 1, 2) | | | 10 | | ms |

The ullet denotes specifications which apply over the full operating temperature range.

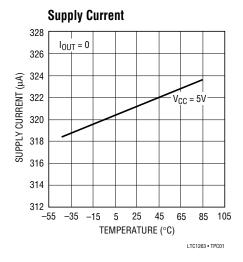
Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

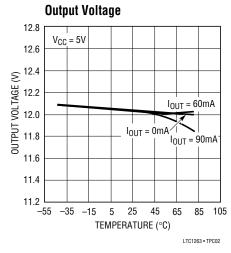
Note 2: All currents into device pins are positive; all currents out of device pins are negative. All voltages are referenced to ground unless otherwise specified.

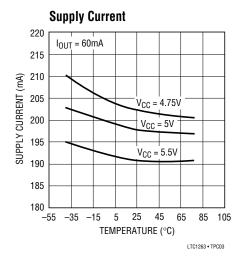
Note 3: All typicals are given at $V_{CC} = 5V$, $T_A = 25$ °C.

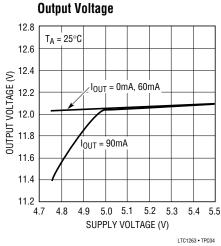
Note 4: A higher value output capacitor can be used but the "turn-on" and "turn-off" time will increase proportionally.

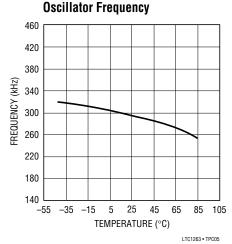
TYPICAL PERFORMANCE CHARACTERISTICS











PIN FUNCTIONS

C1⁻ (**Pin 1**): First Charge Capacitor Negative Input. Connect a 0.47μF capacitor (C1) between C1⁺ and C1⁻.

C1+ (**Pin 2**): First Charge Capacitor Positive Input. Connect a 0.47μF capacitor (C1) between C1+ and C1-.

C2⁻ (**Pin 3**): Second Charge Capacitor Negative Input. Connect a 0.47μF capacitor (C2) between C2⁺ and C2⁻.

C2⁺ (**Pin 4**): Second Charge Capacitor Positive Input. Connect a 0.47μF capacitor (C2) between C2⁺ and C2⁻.

V_{CC} (Pin 5): Positive Supply Input. $4.75V \le V_{CC} \le 5.5V$. Requires a 10 μ F bypass capacitor to ground (C4).

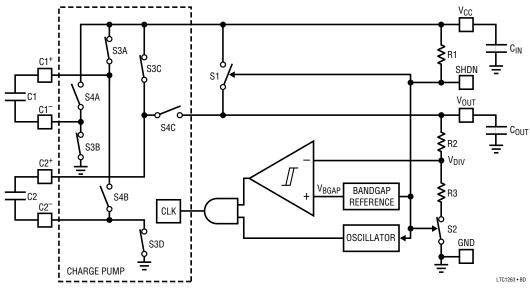
 V_{OUT} (Pin 6): 12V Output. Requires a $10\mu F$ or a higher value bypass capacitor to ground (C3). $V_{OUT} = V_{CC}$ when in the shutdown mode.

GND (Pin 7): Ground.

SHDN (Pin 8): Active-High TTL Logic Level Shutdown Pin. SHDN is internally pulled up to V_{CC} . Connect to GND for normal operation. In shutdown mode, the charge pump is turned off and $V_{OUT} = V_{CC}$.

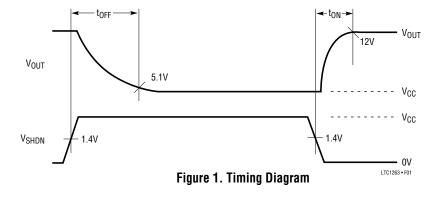


BLOCK DIAGRAM



S1 AND S2 SHOWN WITH SHDN PIN LOW. S3A, S3B, S3C, S3D, S4A, S4B AND S4C SHOWN CHARGING C1 AND C2 WITH OSCILLATOR OUTPUT LOW AND $V_{\rm DIV}$ < $V_{\rm BGAP}$ – $V_{\rm HYST}$. AT OSCILLATOR OUTPUT HIGH, S3A, S3B, S3C AND S3D OPEN WHILE S4A, S4B AND S4C CLOSE TO CHARGE $V_{\rm OUT}$. COMPARATOR HYSTERESIS IS $\pm V_{\rm HYST}$

TIMING DIAGRAMS



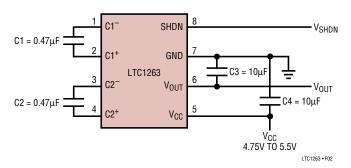


Figure 2. Timing Circuit



OPERATION

The LTC1263 uses a charge pump tripler to generate 12V from a V_{CC} of 5V. The charge pump is clocked by an internal oscillator. The oscillator frequency is not critical and may vary from the typical value of 300kHz. When the oscillator output is low, C1 and C2 are each connected between V_{CC} and GND, charging them to V_{CC} (see Figure 3). When the oscillator output goes high, C1 and C2 are stacked in series with the bottom plate of C1 pulled to V_{CC} (see Figure 4). The top plate of C2 is switched to charge C_{OLIT} , which enables V_{OLIT} to rise.

 V_{OUT} is regulated to within 5% of 12V by an oscillator pulse gating scheme that turns the charge pump on and off based on the comparator results of V_{OUT} and a reference voltage. First, a resistor divider senses V_{OUT} ; if the output of the divider (V_{DIV}) is less than the output of a bandgap (V_{BGAP}) by the hysteresis voltage (V_{HYST}) of the comparator, then oscillator pulses are applied to the charge pump to raise V_{OUT} . When V_{DIV} is above V_{BGAP} by V_{HYST} , the

GND and the higher of either V_{OUT} or V_{CC} .

To reduce supply current, the LTC1263 may be put into shutdown mode by "floating" the SHDN pin or connecting it to V_{CC} . In this mode, the bandgap, comparator, oscillator and resistor divider are switched off to reduce the supply current to typically 0.5 μ A. At the same time an internal switch shorts V_{CC} to V_{CC} ; V_{CC} takes 10ms (typically 0.5 μ A).

oscillator pulses are prevented from clocking the charge

pump. As a result, V_{OIIT} drops until V_{DIV} is below V_{RGAP} by

To ensure proper start-up when V_{OUT} is lower than V_{CC}

and maintain proper operation when V_{OUT} is higher than

V_{CC}, the gates of all internal switches are driven between

 V_{HYST} again.

internal switch shorts V_{OUT} to V_{CC} ; V_{OUT} takes 10ms (typ) to reach 5.1V (see t_{OFF} in Figure 1). When the SHDN pin is low, the LTC1263 exits shutdown and the charge pump operates to raise V_{OUT} to 12V. V_{OUT} takes 600 μ s (typ) to reach the lower regulation limit of 11.4V (see t_{ON} in Figure 1).

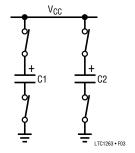


Figure 3. C1 and C2 Charge to V_{CC}

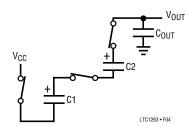


Figure 4. C1 and C2 Stacked in Series with C1⁻ Tied to V_{CC}

APPLICATIONS INFORMATION

Choice of Capacitors

The LTC1263 is tested with the capacitors shown in Figure 2. C1 and C2 are $0.47\mu F$ ceramic capacitors and C_{IN} and C_{OUT} are $10\mu F$ tantalum capacitors. Refer to Table 1 if other choices are desired.

Table 1. Recommended Capacitor Types and Values

| | CAPACITOR | TOR CERAMIC TANTALUM | | ALUMINUM | | |
|--|------------------|----------------------|-----------------|-----------------|--|--|
| | C1, C2 | 0.47μF to 1μF | Not Recommended | Not Recommended | | |
| | C _{OUT} | 10μF (Min) | 10μF (Min) | 10μF (Min) | | |
| | C _{IN} | 10μF (Min) | 10μF (Min) | 10μF (Min) | | |

C1 and C2 should be ceramic capacitors with values in the range of $0.47\mu F$ to $1\mu F$. Higher values provide better load regulation. Tantalum capacitors are not recommended as the higher ESR of these capacitors degrades performance at high load currents and $V_{CC} = 4.75V$.

 C_{IN} and C_{OUT} can be ceramic, tantalum or electrolytic capacitors. The ESR of C_{OUT} introduces steps in the V_{OUT} waveform whenever the charge pump charges C_{OUT} . This tends to increase V_{OUT} ripple. Ceramic or tantalum capacitors are recommended for C_{OUT} if minimum ripple is



APPLICATIONS INFORMATION

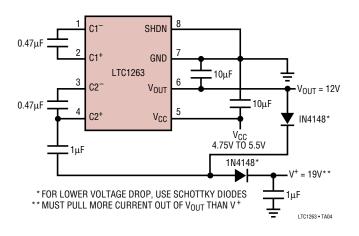
desired. (The LTC1263 does not require a $0.1\mu F$ capacitor between V_{CC} and V_{OUT} for stability.)

Besides using it to program flash memories, the LTC1263 can also provide multiple supply voltages with the help of

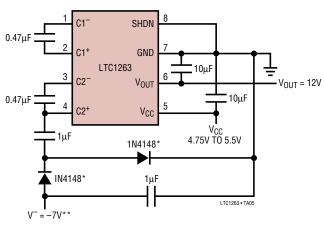
two diodes and two capacitors. Output voltages of 19V and -7V can easily be obtained. In other words, the LTC1263 can power dual supply $(\pm 5V)$ and single supply (15V) op amps.

TYPICAL APPLICATIONS

Dual Voltage Supply Output at 12V and 19V

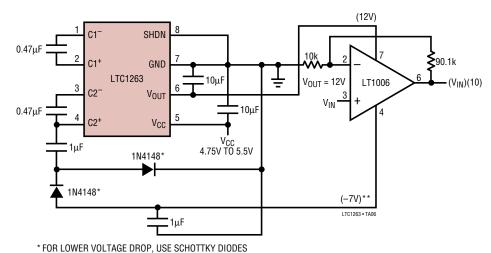


Dual Supply Voltage Output at 12V and -7V



*FOR LOWER VOLTAGE DROP, USE SCHOTTKY DIODES **MUST PULL MORE CURRENT OUT OF V_{OUT} THAN V^-

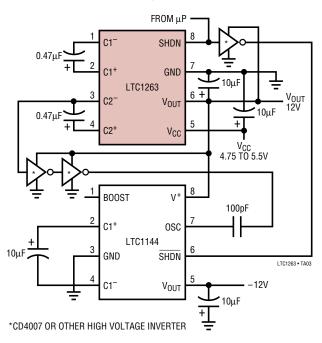
Gain of 10 Amplifier Using LT® 1006 Powered by LTC1263



** MUST PULL MORE CURRENT OUT OF V_{OUT} THAN V

TYPICAL APPLICATIONS

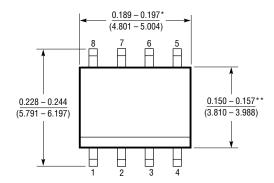
Dual Voltage Supply Output at 12V and -12V

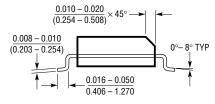


PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.

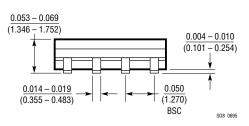
S8 Package 8-Lead Plastic Small Outline (Narrow 0.150)

(LTC DWG # 05-08-1610)





- *DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE
- **DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE





TYPICAL APPLICATION

SHDN GND LTC1263 10uF V_{OUT} . 12V V_{OUT} 60mA V_{IN} 5V V_{CC} $220\mu F'$ 8V $\times 3$ TP0610 Si4410DY 3μH 10A 0.01Ω V_{OUT} 3.3V P DRIVE VN2222 100Ω 5A SHDN SENSE+ SHUTDOWN LTC1148-3.3 1000pF MBRS120T3 330μF SENSE-6.3V OS-CON $\times 2$ **≨**510Ω N DRIVE C_T **←** Si4410DY 150pF SGND **PGND** 3300pF Burst ModeTM OPERATION DEFEAT; USE IF REQUIRED LTC1263 • TA07 *PANASONIC BCGCOKB220R OR EQUIVALENT

5V to 3.3V/5A Converter with 12V/60mA Auxiliary Output

Burst Mode IS A TRADEMARK OF LINEAR TECHNOLOGY CORPORATION

RELATED PARTS

| PART NUMBER | DESCRIPTION | COMMENTS |
|----------------------|--|---|
| LTC1044A | 12V CMOS Voltage Converter | 1.5V to 12V Supply Range, 95% Efficiency, ±V _{OUT} |
| LT1106/LT1107/LT1108 | Micropower DC/DC Converter, 5V and 12V | Adjustable V _{OUT} from V _{IN} = 3V, Use Inductor |
| LTC 1262 | 12V, 30mA Flash Memory Program Supply | 1/2 Source Current as LTC1263, Cannot Short V _{OUT} to GND |
| LT1301/LT1302/LT1303 | Micropower High Efficiency 5V/12V, DC/DC Converter | 5V at 600mA or 12V at 120mA, Use Inductor |
| LT1312 | Single PCMCIA VPP Driver/Regulator | 120mA Output, Current Limit, Thermal Shutdown |
| LTC1429 | Regulating Positive to Negative Charge Pump | Fixed –4.1V or Adjustable Output, No Inductors |

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NCP81109GMNTXG SCY1751FCCT1G NCP81109JMNTXG AP3409ADNTR-G1 NCP81241MNTXG LTM8064IY LT8315EFE#TRPBF

LTM4664EY#PBF LTM4668AIY#PBF NCV1077CSTBT3G XCL207A123CR-G MPM54304GMN-0002 MPM54304GMN-0004

MPM54304GMN-0003 AP62300Z6-7 MP8757GL-P MIC23356YFT-TR LD8116CGL HG2269M/TR OB2269 XD3526 U6215A U6215B

U6620S LTC3412IFE LT1425IS MAX25203BATJA/VY+ MAX77874CEWM+ XC9236D08CER-G MP3416GJ-P BD9S201NUX-CE2

MP5461GC-Z MPQ4415AGQB-Z MPQ4590GS-Z MAX38640BENT18+T MAX77511AEWB+